	Туре	L#	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	230	1/5////5 CCIE	US-PGPUB; USPAT; USOCR	
2	BRS	L2	1249	1/5/1/3/LCCIE	US-PGPÜB; USPAT; USOCR	
3	BRS	L3	186		US-PGPUB; USPAT; USOCR	
4	BRS	L4	28	257/744.ccls.	11 1 H K W/W H M I .	2006/08/14 16:24
5	BRS	L5	92	257/745.ccls.	EPO; JPO; DERWENT; IBM_TDB	2006/08/14 16:24
6	BRS	L6	393	257/734.ccls.	EPO; JPO; DERWENT; IBM_TDB	2006/08/14 16:24
7	BRS	L7	7	((GaN or group adj III-V) and metal and (oxygen or oxide) and electrode and (La or Ce or Pr or Nd or Pm or Sm or Eu)).clm.		2006/08/14 16:27
8	BRS	L8	4	((GaN or group adj III-V) and nitride and metal and (oxygen or oxide) and electrode and (La or Ce or Pr or Nd or Pm or Sm or Eu)).clm.	US-PGPUB	2006/08/14 16:27
9	BRS	L9	2	((GaN or group adj III-V) and nitride and metal and (oxygen or oxide) and electrode and (Gd or Tb or Dy or Ho or Er or Tm or Yb or Lu)).clm.	US-PGPUB	2006/08/14 16:28